RICHTEK®

500mA, Low Dropout, Low Noise, Ultra-Fast Linear Regulator

General Description

The RT9065 is designed for portable RF and wireless applications with demanding performance and space requirements. The RT9065 performance is optimized for battery powered systems to deliver ultra low noise and low quiescent current. A noise bypass pin is available for further reduction of output noise. Regulator ground current increases only slightly in dropout, further prolonging the battery life. The RT9065 also works with low-ESR ceramic capacitors, reducing the amount of board space necessary for power applications, critical in hand held wireless devices. The RT9065 consumes less than $0.01 \mu A$ in shutdown mode and has fast turn-on time less than 10µs. The other features include low dropout voltage, high output accuracy, current limiting protection, and high ripple rejection ratio. The RT9065 is available in the SOT-23-6 package.

Ordering Information

RT9065

└ Package Type E : SOT-23-6

-Lead Plating System

G : Green (Halogen Free and Pb Free)

Note :

Richtek products are :

- ▶ RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.

Features

- Ultra-Low-Noise for RF Application
- Ultra-Fast Response in Line/Load Transient
- Quick Start-Up (Typically 10μs)
- 0.01µA Shutdown Current
- Low Dropout : 370mV @ 500mA
- Wide Input Voltage Range : 2.2V to 5.5V
- Adjustable Output Voltage
- TTL Logic Controlled Shutdown Input
- Low Temperature Coefficient
- Current Limiting Protection
- Thermal Shutdown Protection
- Only 1µF Output Capacitor Required for Stability
- High Power Supply Rejection Ratio
- RoHS Compliant and Halogen Free

Applications

- CDMA/GSM Cellular Handsets
- Battery Powered Equipment
- Laptop, Palmtops, Notebook Computers
- Hand Held Instruments
- PCMCIA Cards
- Portable Information Appliances

Marking Information

0B=DNN

0B= : Product Code DNN : Date Code

Simplified Application Circuit



Pin Configurations



Functional Pin Description

Pin No.	Pin Name	Pin Function
1	VIN	Power Input.
2	GND	Ground.
3	EN	Chip Enable (Active High). Note that this pin is high impedance. There should be a pull-low $100k\Omega$ resistor connected to GND when the control signal is floating.
4	BP	Reference Noise Bypass.
5	ADJ	Feedback Input. Connect a resistive divider to adjust the output voltage.
6	VOUT	Output of the Regulator.

Function Block Diagram



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Operation

The RT9065 is a low dropout voltage linear regulator designed for RF and wireless applications which require low noise and high PSRR performance. The RT9065 builds in a P-type P-MOSFET with current capability up to 500mA. In normal operation, the Error Amplifier adjusts the gate voltage of the power MOSFET to regulate the ADJ voltage being equal to the internal 0.8V reference voltage.

P-MOSFET current is detected and current limit function will work to limit the output current to a designed value when short circuit happens. Furthermore, the P-MOSFET will be shutdown if the junction temperature is higher than typically 165°C, and released to normal operation until the temperature falls below typically 135°C.

Quick Start

This function is designed to achieve internal reference voltage quick ramping up during chip turning on or power on.

Shutdown and Logic Control

This function block includes chip Enable/Disable and UVLO circuits. When chip is disabled, VOUT is pulled to GND through the auto-discharge MOSFET.



Absolute Maximum Ratings (Note 1)

Supply Voltage, VIN	-0.3V to 6V
Chip Enable Input Voltage, EN	-0.3V to 6V
Output Voltage, VOUT	-0.3V to 6V
Adjust Output, ADJ	-0.3V to 6V
• Power Dissipation, $P_D @ T_A = 25^{\circ}C$	
SOT-23-6	0.48W
Package Thermal Resistance (Note 2)	
SOT-23-6, θ _{JA}	208.2°C/W
SOT-23-6, θ _{JA} • Lead Temperature (Soldering, 10 sec.)	208.2°C/W 260°C
SOT-23-6, θ _{JA} • Lead Temperature (Soldering, 10 sec.) • Storage Temperature Range	208.2°C/W 260°C -65°C to 150°C
SOT-23-6, θ _{JA} • Lead Temperature (Soldering, 10 sec.) • Storage Temperature Range • Junction Temperature	208.2°C/W 260°C -65°C to 150°C 150°C
SOT-23-6, θ _{JA} • Lead Temperature (Soldering, 10 sec.) • Storage Temperature Range • Junction Temperature • ESD Susceptibility (Note 3)	208.2°C/W 260°C –65°C to 150°C 150°C
SOT-23-6, θ _{JA} • Lead Temperature (Soldering, 10 sec.) • Storage Temperature Range • Junction Temperature • ESD Susceptibility (Note 3) HBM (Human Body Model)	208.2°C/W 260°C -65°C to 150°C 150°C 2kV

Recommended Operating Conditions (Note 4)

•	Supply Voltage, VIN	2.2V to 5.5V
•	Junction Temperature Range	-40° C to 125° C
•	Ambient Temperature Range	–40°C to 85°C

Electrical Characteristics

(V_{IN} = V_{OUT} + 1V, C_{IN} = 2.2μ F, C_{OUT} = 1μ F, C_{BP} =22nF, T_A = 25° C, unless otherwise specified)

Param	eter	Symbol	Test Conditions	Min	Тур	Max	Unit	
ADJ Reference Voltage		V _{ADJ}	$V_{IN} = 5V, I_{OUT} = 100 \text{mA}$	0.788	0.8	0.812	V	
Shutdown Current		I _{SHDN}	V _{EN} = GND		0.01	1	μA	
Quiescent Current		l _Q	I _{OUT} = 0mA		90	120	μA	
Dropout Voltage		V _{DROP}	I _{OUT} = 300mA		220	300	mV	
			I _{OUT} = 500mA		370	500		
Line Regulation		ΔV_{LINE}	$V_{IN} = (V_{OUT} + 1V)$ to 5.5V, $I_{OUT} = 1mA$			0.3	%	
Load Regulation		ΔV_{LOAD}	1mA < I _{OUT} < 500mA			0.6	%	
EN Input Bias C	Current	I _{IBSD}	$V_{EN} = GND \text{ or } V_{IN}$		0	100	nA	
EN Input	Logic-High	V _{IH}		1.2			V	
Voltage	Logic-Low	V _{IL}				0.4	v	
Output Noise Voltage		e _{NO}	10kHz to 100kHz, I_{OUT} = 200mA, C _{OUT} = 1µF		100		μV_{RMS}	
Power Supply	f = 100Hz	PSRR	$C_{OUT} = 1\mu F$, $I_{OUT} = 10mA$		70		dB	
Rejection Rate	f = 10kHz				50		uБ	
Under Voltage Lockout Threshold		V _{UVLO}	V _{IN} Rising	1.6	1.8	2	V	

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Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Under Voltage Lockout Hysteresis	ΔV_{UVLO}		0.1	0.15		V
Current Limit	I _{LIM}	$R_{LOAD} = 1\Omega$	500	650		mA
Thermal Shutdown Threshold	T _{SD}			165		°C
Hysteresis	ΔT_{SD}			30		°C

Note 1. Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Note 2. θ_{JA} is measured at $T_A = 25^{\circ}C$ on a high effective thermal conductivity four-layer test board per JEDEC 51-7.

Note 3. Devices are ESD sensitive. Handling precaution recommended.

Note 4. The device is not guaranteed to function outside its operating conditions.



Typical Application Circuit



Typical Operating Characteristics



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Output Current (mA)

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Application Information

The RT9065 requires input and output decoupling capacitors. These capacitors must be correctly selected for good performance and insufficient decoupling capacitance may cause oscillation.

Input Capacitor

The value of input capacitor should be $\ge 2.2\mu$ F. The input capacitor must be placed within 1cm from the device to assure input stability. There are no requirements for the ESR (equivalent series resistance) on the input capacitor, but low-ESR ceramic capacitor with larger value provides better PSRR and line transient response.

Output Capacitor

The output capacitor must meet both requirements for minimum amount of capacitance and ESR for the LDO application. The RT9065 is designed specifically to work with low-ESR ceramic output capacitor in consideration of space-saving and performance. To ensure the stability, the value of ceramic capacitor should be at least 1µF and ESR should be > $5m\Omega$. The RT9065 can also work well with other types of output capacitors. Figure 1 shows the stable range of ESR as a function of load current for various output capacitor values. Output capacitor with larger capacitance can reduce noise and improve load transient response, stability, and PSRR. The output capacitor should be located no more than 0.5 inches from the VOUT pin.



Region of Stable COUT ESR vs. Output Current

Figure 1. Region of Stable COUT ESR

Adjustable Output Voltage

The output voltage is set by the ratio of two external resistors as follow :

 $V_{OUT} = 0.8 \times (1 + R1/R2)$

Bypass Capacitor and Low Noise

Connecting a 22nF capacitor between the BP pin and the GND pin significantly reduces noise on the regulator output, and it is critical that the capacitor should be placed close to the IC and PCB traces should be as short as possible. DC leakage on this pin can affect the LDO regulator output noise and voltage regulation performance.

Enable Function

The RT9065 features an enable/disable function. The enable control level must be greater than 1.2V to turn-on the device. When the voltage on the EN pin falls below 0.4V, the LDO will be shut down and will reduce guiescent current to less than 1µA. If the enable function is not needed in a specific application, it should be tied to VIN to keep the LDO in a continuously on state.

Current Limit

The RT9065 contains an independent current limiter, which monitors and controls the pass transistor's gate voltage, limiting the output current to 0.65A (typ.). The output can be shorted to ground without damaging the part.

Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

 $\mathsf{P}_{\mathsf{D}(\mathsf{MAX})} = (\mathsf{T}_{\mathsf{J}(\mathsf{MAX})} - \mathsf{T}_{\mathsf{A}}) / \theta_{\mathsf{J}\mathsf{A}}$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

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For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to SOT-23-6 package, the thermal resistance, θ_{JA} , is 208.2°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at $T_A = 25^{\circ}C$ can be calculated by the following formula :

 ${\sf P}_{D(MAX)}$ = (125°C - 25°C) / (208.2°C/W) = 0.48W for SOT-23-6 package

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance, θ_{JA} . The derating curve in Figure 2 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.



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Figure 2. Derating Curve of Maximum Power Dissipation

Outline Dimension



Our set of	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Мах	Min	Max	
А	0.889	1.295	0.031	0.051	
A1	0.000	0.152	0.000	0.006	
В	1.397	1.803	0.055	0.071	
b	0.250	0.560	0.010	0.022	
С	2.591	2.997	0.102	0.118	
D	2.692	3.099	0.106	0.122	
е	0.838	1.041	0.033	0.041	
Н	0.080	0.254	0.003	0.010	
L	0.300	0.610	0.012	0.024	

SOT-23-6 Surface Mount Package

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